2N5781 PNP 2N5784 NPN

COMPLEMENTARY SILICON POWER TRANSISTORS



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N5781 and 2N5784 types are Complementary Silicon Power Transistors designed for general purpose switching and amplifier applications.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T _C =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	VCER	80	V
Collector-Emitter Voltage	VCEO	65	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Continuous Collector Current	l _C	3.5	Α
Continuous Base Current	lΒ	1.0	Α
Power Dissipation	P_{D}	10	W
Power Dissipation (T _A =25°C)	P_{D}	1.0	W
Operating and Storage Junction Temperature	Т _Ј , Т _{stg}	-65 to +200	°C
Thermal Resistance	ΘJC	17.5	°C/W
Thermal Resistance	Θ_{JA}	175	°C/W

	JA.			
ELECTRICAL	CHARACTERISTICS: (T _C =25°C unless otherwise	noted)		
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
ICEV	V_{CE} =75V, V_{BE} =1.5V		10	μΑ
ICEV	V _{CE} =75V, V _{BE} =1.5V, T _C =150°C		1.0	mA
I _{CER}	V_{CE} =65V, R_{BE} =100 Ω		10	μΑ
ICER	$V_{CE}=65V, R_{BE}=100\Omega, T_{C}=150^{\circ}C$		1.0	mA
ICEO	V _{CE} =50V		100	μΑ
I _{EBO}	V _{EB} =5.0V		10	μΑ
BVCER	I_C =10mA, R _{BE} =100Ω	80		V
BVCEO	I _C =10mA	65		V
V _{CE(SAT)}	I _C =1.0A, I _B =100mA		0.5	V
V _{BE} (ON)	V _{CE} =2.0V, I _C =1.0A		1.5	V
h _{FE}	V_{CE} =2.0V, I_{C} =1.0A	20	150	
hFE	V _{CE} =2.0V, I _C =3.2A	4.0		
fT	V _{CE} =2.0V, I _C =100mA, f=4.0MHz (2N5781)	8.0	60	MHz
f _T	V _{CE} =2.0V, I _C =100mA, f=200kHz (2N5784)	1.0	4.0	MHz
h _{fe}	V _{CE} =2.0V, I _C =100mA, f=1.0kHz	25		
ton	V _{CC} =30V, I _C =1.0A, I _{B1} =I _{B2} =100mA (2N5781)		0.5	μs
ton	V _{CC} =30V, I _C =1.0A, I _{B1} =I _{B2} =100mA (2N5784)		5.0	μs
toff	V _{CC} =30V, I _C =1.0A, I _{B1} =I _{B2} =100mA (2N5781)		2.5	μs
toff	V _{CC} =30V, I _C =1.0A, I _{B1} =I _{B2} =100mA (2N5784)		15	μs

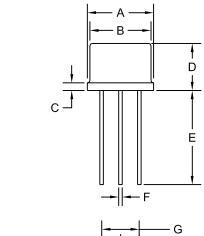
R1 (25-January 2011)

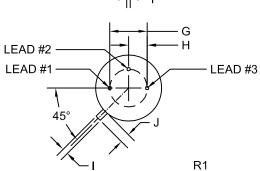
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TO-39 CASE - MECHANICAL OUTLINE





DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
A (DIA)	0.335	0.370	8.51	9.40			
B (DIA)	0.315	0.335	8.00	8.51			
С	-	0.040	-	1.02			
D	0.240	0.260	6.10	6.60			
Е	0.500	-	12.70	-			
F (DIA)	0.016	0.021	0.41	0.53			
G (DIA)	0.200		5.08				
Н	0.100		2.54				
	0.028	0.034	0.71	0.86			
J	0.029	0.045	0.74	1.14			

TO-39 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

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- Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- · PbSn plating options
- Package details
- · Application notes
- · Application and design sample kits
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CONTACT US

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